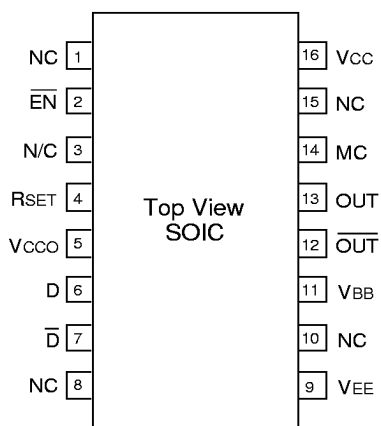


FEATURES

- Up to 1.2Gbit/s operation
- 75mA peak drive current
- Separate modulation control
- Separate output enable for laser safety
- Differential inputs for data
- 75K Ω input pulldown resistor
- Single power supply

PIN CONFIGURATION



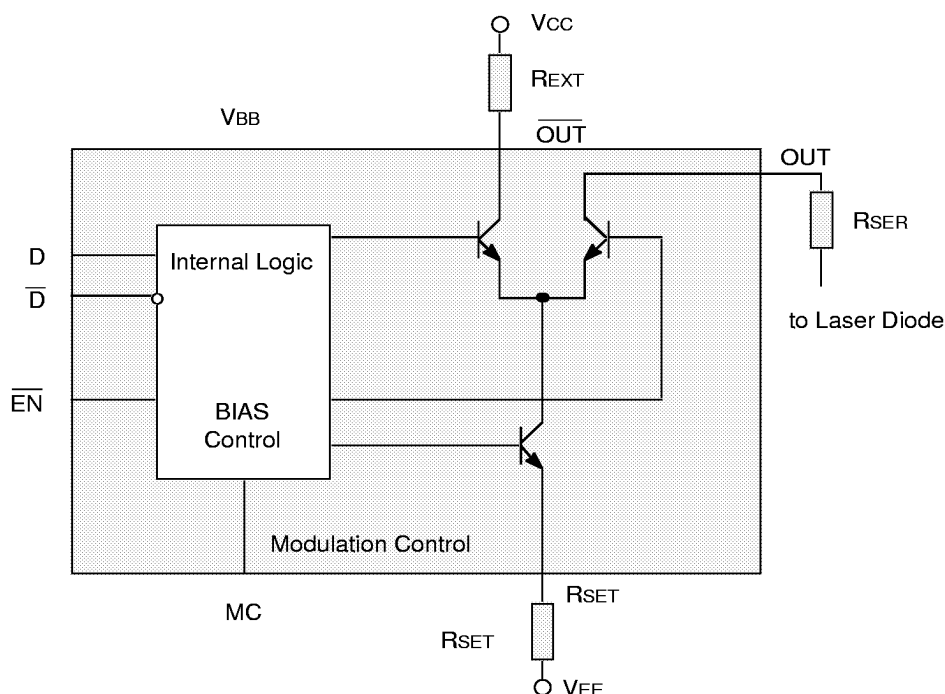
DESCRIPTION

The SY100EL1003 is a high speed current source for driving a semiconductor laser diode in optical transmission applications. The output current modulation is DC – voltage controlled. The modulation current is disabled when output enable is HIGH.

The device incorporates complementary open collector outputs with a capability of driving peak current of 75mA. The laser driver current is adjustable by selection of RSET. The resistor REXT must be placed between $\overline{\text{OUT}}$ and VCC to dissipate the worst case power. RSER is recommended to fix laser diode matching issues.

The SY100EL1003 utilizes the high performance bipolar ASSET technology.

BLOCK DIAGRAM



PIN NAMES

Pin	Function
VCC, VCCO	Separate positive power supply pins help to isolate sensitive circuitry from noise generating function. +5V for PECL operation or ground for ECL operation.
VEE	Most negative power supply input. Ground for PECL operation or -5V for ECL operation.
VBB	This pin provides a reference voltage for use in single ended applications or when the input signal is AC coupled into the device.
D, $\bar{D}$	These differential ECL/PECL 100K compatible inputs receive NRZ data.
$\overline{EN}$	This ECL/PECL 100K compatible input enables Laser Driver - modulation current goes to zero when asserted HIGH.
OUT, $\overline{OUT}$	Open collector outputs from the modulation buffer drive these differential current outputs.
MC	An external voltage sets up the main value of modulation current I_o .
RSET	An external resistor sets up the source current for modulation I_{mod} .
NC	These pins are not connected.

TRUTH TABLE⁽¹⁾

D	$\bar{D}$	$\overline{EN}$	OUT	$\overline{OUT}$
L	H	L	H	L
H	L	L	L	H
X	X	H	H	L

NOTE:

1. L = LOW, H = HIGH, X = don't care

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Value	Unit
VEE	Power Supply Voltage ($V_{CC} = 0V$)	0 to -7.0	V
V_I	Input Voltage ($V_{CC} = 0V$)	0 to -6.0	V
I_o	Output Current	75	mA
T_A	Operating Temperature Range	0 to +70	°C
P_{tot}	Power Dissipation	500	mW

NOTE:

- Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to ABSOLUTE MAXIMUM RATING conditions for extended periods may affect device reliability.

OPERATIONING CONDITIONS⁽¹⁾

Symbol	Rating	Value	Unit
VEE	Power Supply Voltage	-4.75 to -5.25	V
RSET	Resistor to Adjust Current	10 to 100	Ω
REXT	Resistor to Dissipate Power	10 to 50	Ω
RSER	Laser Diode Serial Resistor	0 to 50	Ω

NOTE:

- The voltage drop across REXT and RSER should not be greater than 2V.

DC ELECTRICAL CHARACTERISTICS⁽¹⁾

VCC = VCCO = 0V; VEE = -5.0V ± 5%

Symbol	Parameter	TA = 0°C			TA = +25°C			TA = +70°C			Unit	Condition
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
VIH	Input HIGH Voltage (D, EN)	-1165	—	-880	-1165	—	-880	-1165	—	-880	mV	
VIL	Input LOW Voltage (D, EN)	-1810	—	-1475	-1810	—	-1475	-1810	—	-1475	mV	
VImod	Input Voltage (Modulation Control)	VEE	—	VCC	VEE	—	VCC	VEE	—	VCC	V	
VBB	Output Reference Voltage	-1380	—	-1260	-1380	—	-1260	-1380	—	-1260	mV	
IIH	Input HIGH Current (D, EN)	—	—	150	—	—	150	—	—	150	μA	
IImod	Input Current (Modulation Control)	—	—	150	—	—	150	—	—	150	μA	
IIL	Input LOW Current (D, EN)	0.5	—	—	0.5	—	—	0.5	—	—	μA	VI = VIL(Min.)
ICC	Supply Current	8	14	25	8	14	25	8	14	25	mA	VImod = VCC
IOH	Output HIGH Current (EN LOW)	60 —	64 —	68 5	60 —	64 —	68 5	60 —	64 —	68 5	mA	VImod = -3.5V VImod = -0.8V
IoL	Output LOW Current (EN HIGH)	—	—	500	—	—	500	—	—	500	μA	
IOR	Output Current Ringing	—	—	10	—	—	10	—	—	10	%	IOH = 5 to 60mA
IoMod	Laser Diode Modulation Current Range	5	—	60	5	—	60	5	—	60	mA	

NOTE:

1. RSET = 10Ω ±1%.

AC ELECTRICAL CHARACTERISTICS⁽¹⁾

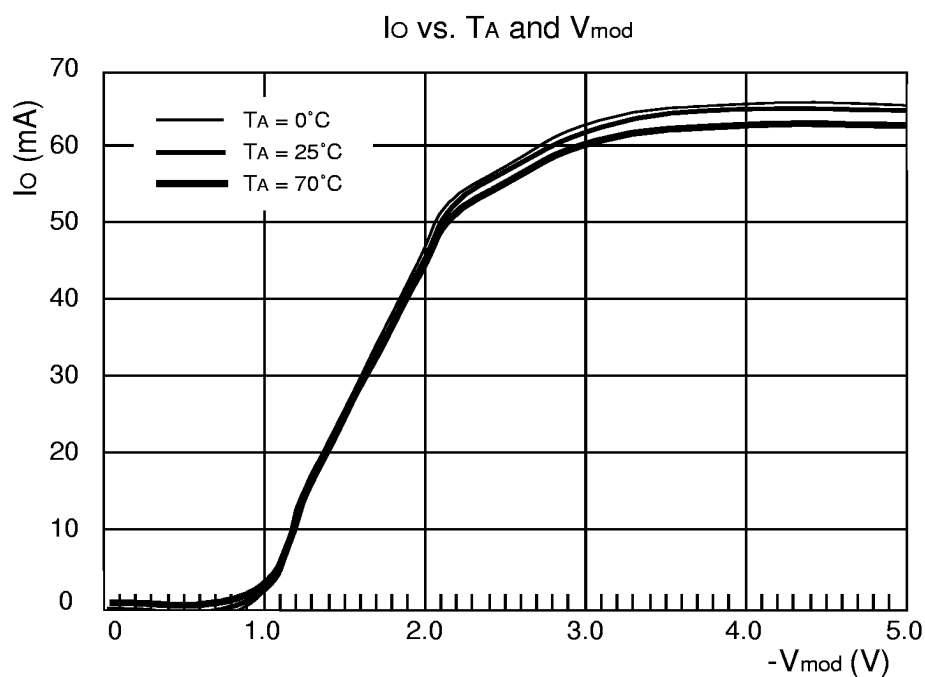
VImod = -1.5V; VCC = VCCO = 0V; VEE = -5V ± 5%

Symbol	Parameter	TA = 0°C			TA = +25°C			TA = +70°C			Unit	Condition
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
t _{pd} D	Propagation Delay D - OUT	—	—	1000	—	—	1000	—	—	1000	ps	
t _{pd} EN	Propagation Delay EN - OUT	—	—	1000	—	—	1000	—	—	1000	ps	
t _r t _f	Rise/Fall Time (20% to 80%)	—	—	400	—	—	400	—	—	400	ps	

NOTE:

1. RSET = 10Ω ±1%, REXT = RSER = 50Ω ±1%

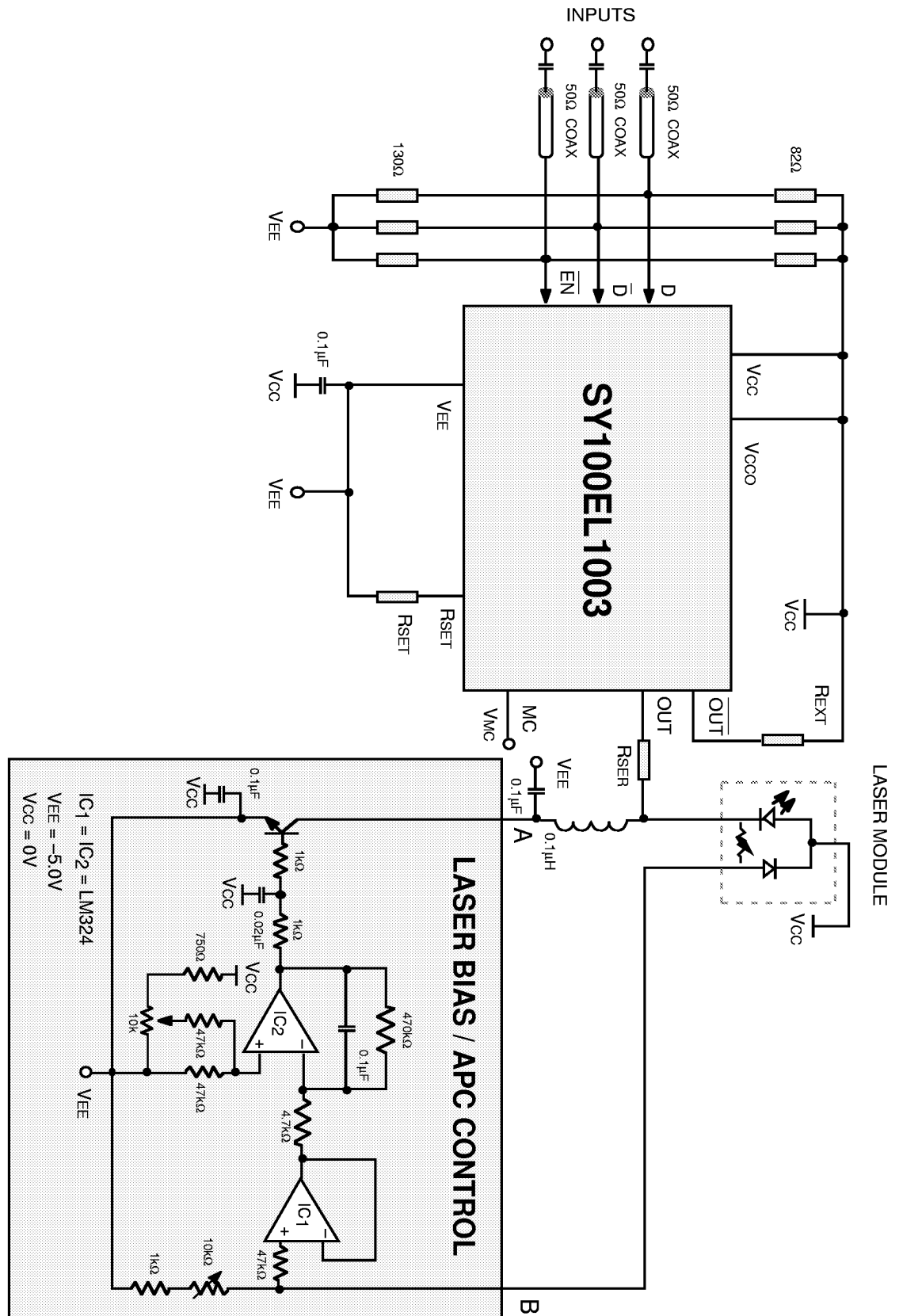
PERFORMANCE CURVES



PRODUCT ORDERING CODE

Ordering Code	Package Type	Operating Range
SY100EL1003ZC	Z16-2	Commercial
SY100EL1003ZCTR	Z16-2	Commercial

APPLICATION EXAMPLE



NOTES:

1. Split 100K ECL terminations are 82Ω and 130Ω to VCC and VEE respectively.
2. Recommended power supply bypass capacitors are 0.1μF with optional 10μF Tantalum in parallel.
3. It is required to use high frequency design techniques for board layout. A double sided or multilayer board is recommended in conjunction with a low impedance ground plane and properly terminated transmission lines for all signal paths.
4. VEE voltage pin may be used as reference for single ended input applications.